

## Latching Hall Switch Sensor

XL539

## Features

- Wide Operating Voltage Range: 3.3V~90V
- Anti-Surge of Output Terminal:  $\geq 90V$
- Reverse Supply Protection
- Device HBM ESD Classification Level Class3B
- Temperature Grade 0:  $-40^{\circ}\text{C}$  to  $150^{\circ}\text{C}$   
Ambient Operating Temperature Range
- Low Quiescent Current: 2.2mA
- 30mA Load Capacity
- Excellent Magnetic Field Symmetry
- Magnetic Field Operate Point : -55Gs
- Magnetic Field Release Point : +55Gs
- TO92S-3 Package

## Applications

- Brushless DC Motors
- Motor and Fan Control System
- Location and Speed Detection

## General Description

The XL539 is a high-voltage, wide-temperature-range latching Hall-effect switch sensor optimized for motor applications, supporting a wide supply voltage range from 3.3V to 90V with low operating current. Adopting a collector open circuit output architecture, XL539 provides a load capacity of up to 30mA, widely used in automotive electronics, industrial control and other applications.

The XL539 integrates a reference voltage source, Hall array, differential comparator, hysteresis latch, and power output stage, providing high magnetic field response sensitivity, symmetry, and strong immunity to electromagnetic interference over the full voltage range and full temperature range.

## Typical application schematic

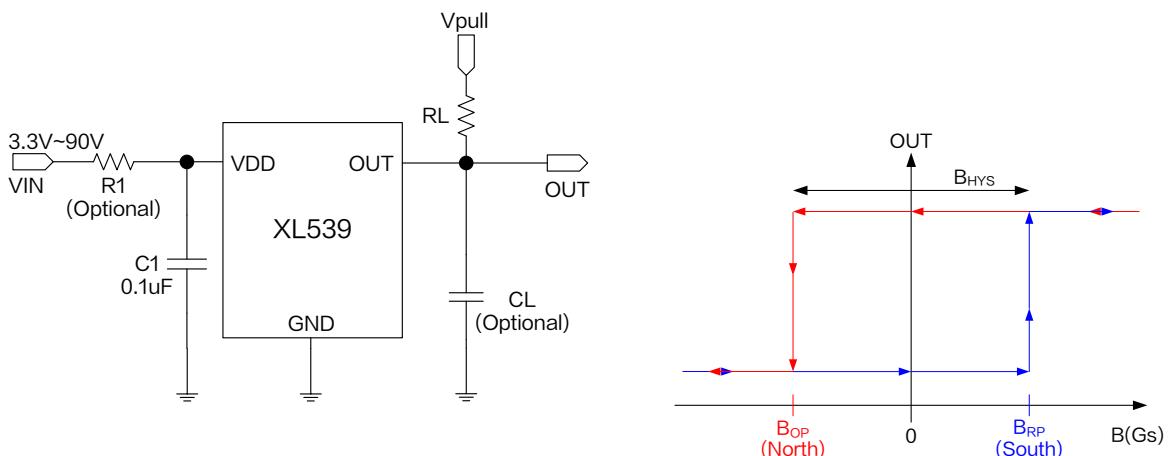


Figure1.XL539 Typical application schematic and output characteristic curve

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## Pin Configurations

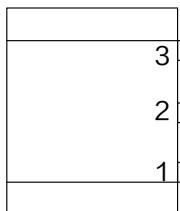


Figure2.Pin Configuration of XL539

Table 1.Pin Description

Pin Number	Pin Name	Description
1	VDD	Supply Voltage Input Pin. XL539 operates from 3.3V to 90V DC voltage.
2	GND	Ground pin.
3	OUT	Open Collector Output Pin, requires a resistor pull-up.

## Ordering Information

Order Information	Marking ID	Package Type	Eco Plan	Packing Type Supplied As
XL539	XL539	TO92S-3	RoHS & HF	1000 Units Per Bag

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## Function Block

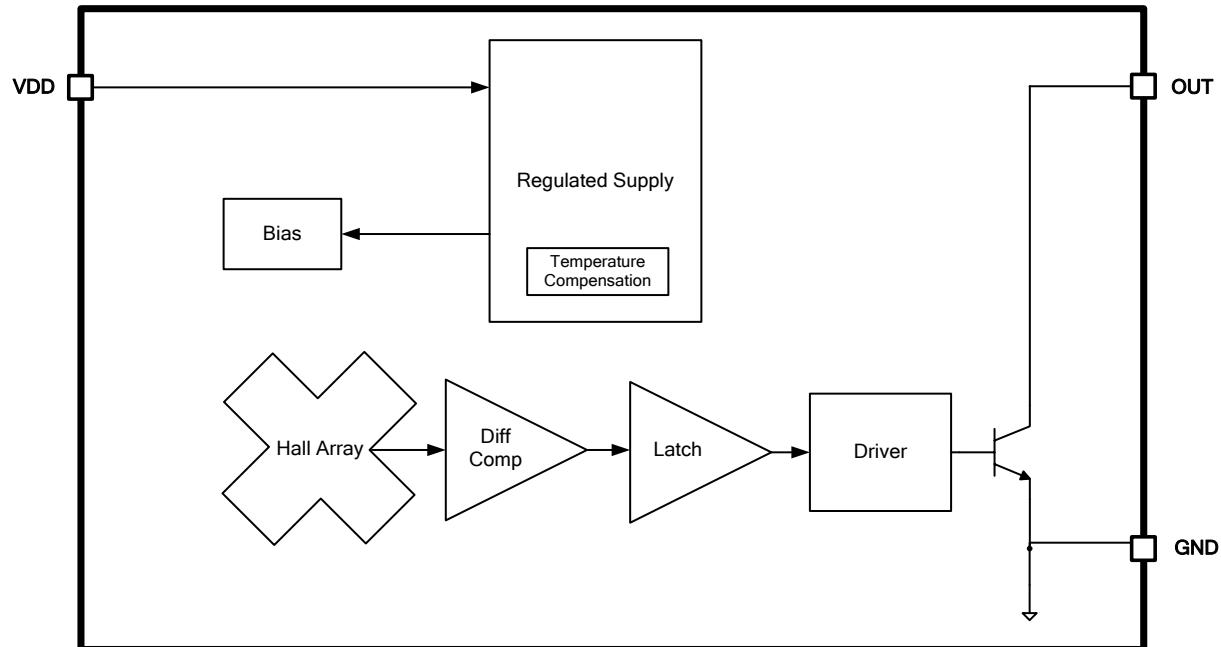


Figure3.Function Block Diagram of XL539

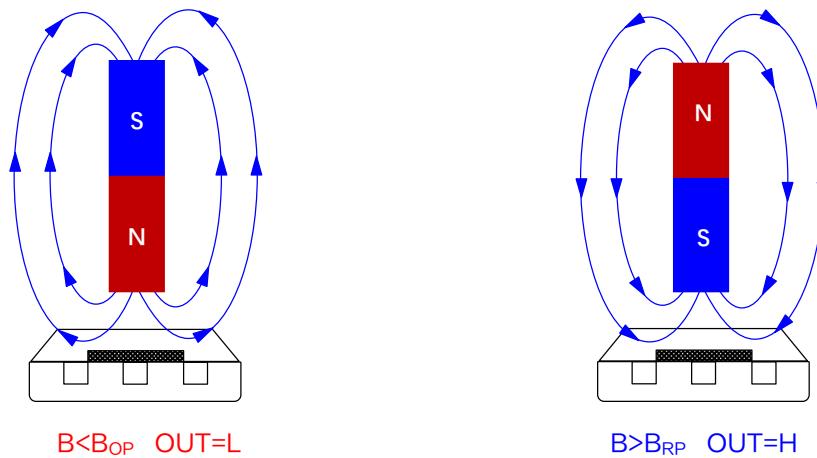


Figure4.Magnetic Field Direction Definition

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## Absolute Maximum Ratings ( Note1 )

Parameter	Symbol	Value	Unit
Input Voltage	$V_{DD}$	-90 ~ 120	V
Output Pin Voltage	$V_{OUT}$	-0.5 ~ 90	V
Output Pin Current Sink	$I_{SINK}$	0 ~ 30	mA
Thermal Resistance (TO92S-3) (Junction to Ambient, No Heatsink, Free Air)	$R_{JA}$	160	°C/W
Operating Temperature	$T_A$	-40 ~ 150	°C
Operating Junction Temperature	$T_J$	-40 ~ 175	°C
Storage Temperature	$T_{STG}$	-65 ~ 175	°C
Lead Temperature (Soldering, 10 sec)	$T_{LEAD}$	260	°C
ESD (HBM)	-	$\geq 8000$	V

**Note1:** Stresses greater than those listed under Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

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## XL539 Electrical Characteristics

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = V_{Pull} = 5\text{V}$ ,  $RL=1\text{k}\Omega$ ,  $R1=0\Omega$ , system parameters test circuit figure1, unless otherwise specified.

Parameters	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operation Voltage	$V_{DD}$	–	3.3	5.0	90	V
Anti-Surge of Input Terminal	$V_{DD\_Surge}$	D=25%, T=20 μs, 10 cycles, $B < B_{Op}$	130	–	–	V
Anti-Surge of Output Terminal	$V_{OUT\_Surge}$	D=25%, T=20 μs, 10 cycles, $B < B_{Op}$	90	–	–	V
Reverse Supply Voltage	$V_{DDR}$	–	-90	–	–	V
Quiescent Current	$I_Q$	OUT=H	–	2.2	–	mA
Operation Supply Current	$I_{DD}$	OUT=L	–	3.2	–	mA
Power-on time	$t_{ON}$	–	–	35	50	μs
Output Saturation Voltage	$V_{CE}$	$I_{OUT}=20\text{mA}$	–	–	0.5	V
Output Delay Time	$t_d$	$B=B_{RP}$ to $B_{Op}$	–	10	25	μs
Output Rise Time	$t_r$	$CL=50\text{pF}$	–	–	0.5	μs
Output Fall Time	$t_f$	$CL=50\text{pF}$	–	–	0.2	μs

## XL539 Magnetic Characteristics ( Note2 )

$T_A = 25^\circ\text{C}$ ,  $V_{DD} = V_{Pull} = 5\text{V}$ ,  $RL=1\text{k}\Omega$ ,  $R1=0\Omega$ , system parameters test circuit figure1, unless otherwise specified.

Parameters	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Bandwidth	$f_{BW}$	–	–	–	100	kHz
Magnetic Field Operate Point	$B_{Op}$	–	-100	-55	-30	Gs
Magnetic Field Release Point	$B_{RP}$	–	+30	+55	+100	Gs
Magnetic Hysteresis	$B_{HYS}$	–	–	110	–	Gs
Magnetic Offset	$B_o$	$B_o=(B_{Op}+B_{RP})/2$	-35	0	+35	Gs

Note2: 1mT=10Gs; A south pole near the marked side of the package is a positive magnetic field; Powering-on the device in the hysteresis region allows an indeterminate output state. The correct state is attained after the first excursion beyond  $B_{Op}$  or  $B_{RP}$ .

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## Typical Characteristics ( Note3 )

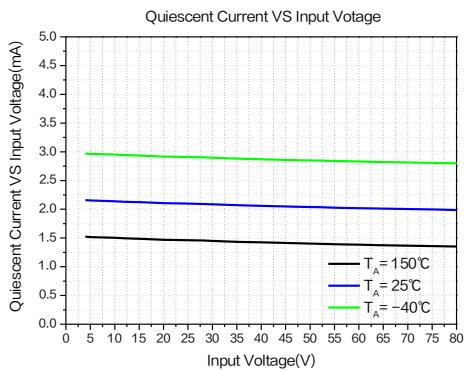


Figure5.Quiescent Current

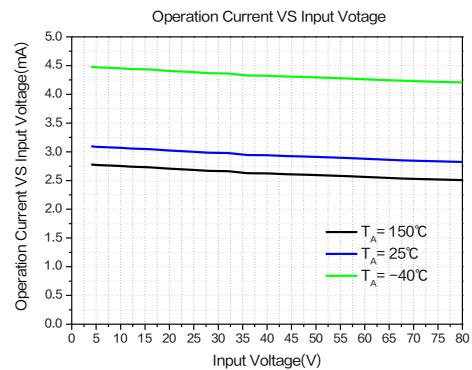


Figure6.Operation Current

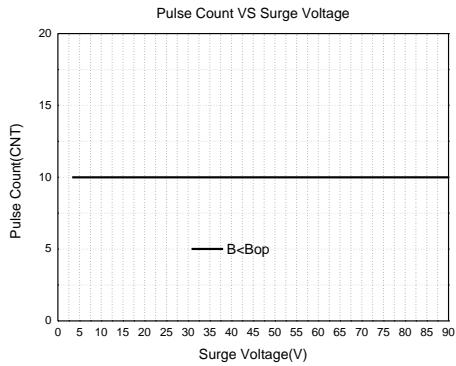


Figure7.Output Terminal Anti Surge Voltage

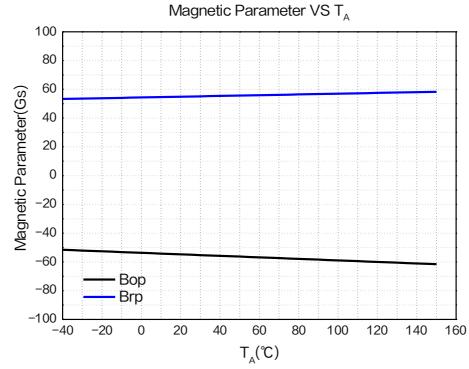


Figure8.Magnetic Operating Point VS Temperature Curve

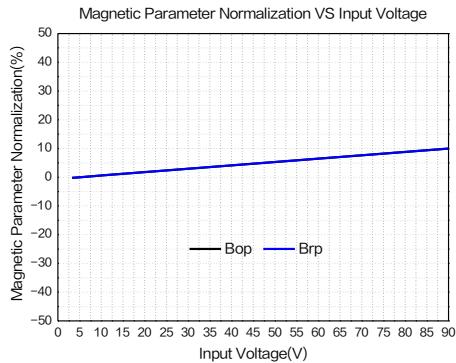


Figure9.Magnetic Operating Point VS Input Voltage Curve

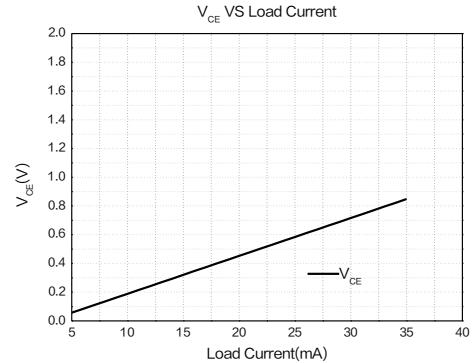


Figure10.Saturation Voltage Drop VS Load Current Curve

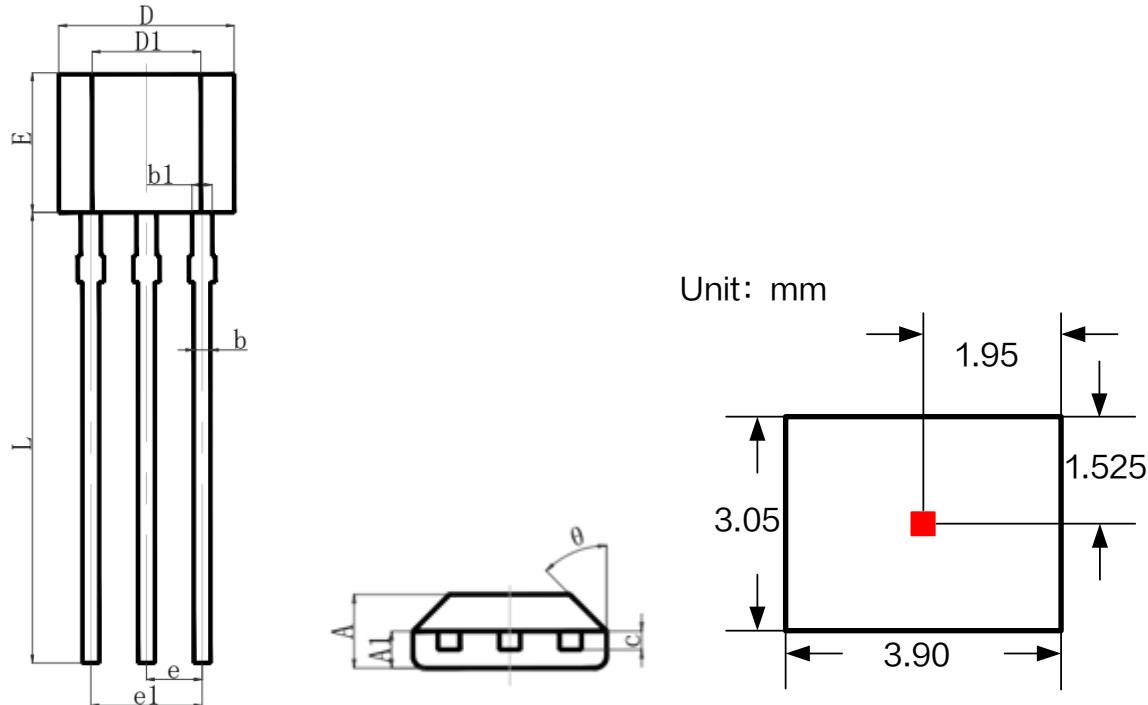
**Note3:** The Surge voltage in Figure 7 is a square wave with a high-level width of 5  $\mu\text{s}$  and a period of 20  $\mu\text{s}$ . This square wave consists of 10 cycles.

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## Package Information

TO92S-3



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.42	1.62	0.056	0.064
A1	0.66	0.87	0.026	0.034
b	0.33	0.56	0.013	0.022
b1	0.40	0.51	0.016	0.020
c	0.33	0.51	0.013	0.020
D	3.90	4.10	0.154	0.161
D1	2.28	2.68	0.090	0.106
E	2.90	3.25	0.114	0.128
e	1.27 REF.		0.050 REF.	
e1	2.44	2.64	0.096	0.104
L	13.50	15.50	0.531	0.610
θ	45° REF.		45° REF.	

**Latching Hall Switch Sensor****XL539****Important Notice**

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